

NTE573-1 & NTE573-2 Schottky Barrier Rectifier DO-201AD Type Package

Features:

- Schottky Barrier Chip
- Guard Ring for Transient and ESD Protection
- Surge Overload Rating to 150A Peak
- Low power Loss, High Efficiency
- Ideally Suited for Use in High Frequency SMPS, Inverters, and as Free Wheeling Diodes

<u>Maximum Ratings and Electrical Characteristics:</u> $(T_A = +25^{\circ}\text{C unless otherwise specified.}$ Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.) Peak Repetitive Reverse Voltage, V_{RRM}
NTE573–1
Working Peak Reverse Voltage, V _{RWM} NTE573-1 100V NTE573-2 200V
DC Blocking Voltage, V _R NTE573-1100V
NTE573-2
RMS Reverse Voltage, V _{R(RMS)} NTE573-1
Average Forward Rectified Current (Note 1), I _O
Non-Repetitive Peak Forward Surge Current, I _{FSM} (8.3ms Single half Sine-Wave Superimposed on Rated Load)
Forward Voltage (I _F = 5A), V _{FM} NTE573-1
Peak Reverse Current (At rated DC Blocking Voltage), I _{RM} T _{.I} = +25°C
NTE573–1
T_J = +100°C NTE573–1
Typical Junction Capacitance (Note 2), C _J NTE573-1
NTE573-2



Note 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

